

## KSD1362

### **B/W TV Horizontal Deflection Output**

Collector- Base Voltage : V<sub>CBO</sub> = 150V
Collector Current : I<sub>C</sub> = 5A

• Collector Dissipation : P<sub>C</sub> = 20W (T<sub>C</sub>=25°C)



## **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	150	V
V <sub>CEO</sub>	Collector-Emitter Voltage	70	V
V <sub>EBO</sub>	Emitter-Base Voltage	8	V
I <sub>C</sub>	Collector Current	5	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

## Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 1 \text{mA}, I_E = 0$	150			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 20$ mA, $R_{BE} = \infty$	70			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 1 \text{mA}, I_C = 0$	8			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 100V, I_{E} = 0$			20	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 5A$	20		140	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 5A, I_B = 0.5A$			1	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 5A, I_B = 0.5A$			1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 0.5A$		10		MHz

## **h**<sub>FE</sub> Classification

Classification	N	R	0	
h <sub>FE</sub>	20 ~ 50	40 ~ 80	70 ~ 140	

# **Typical Characteristics**

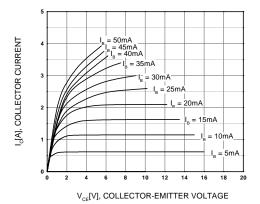


Figure 1. Static Characteristic

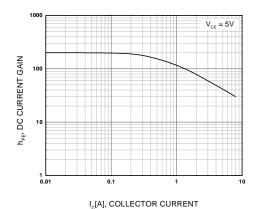


Figure 2. DC current Gain

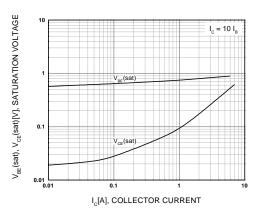


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

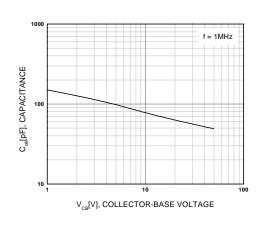


Figure 4. Collector Output Capacitance

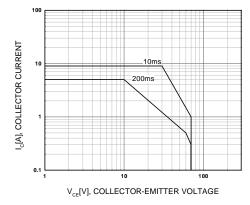


Figure 5. Safe Operating Area

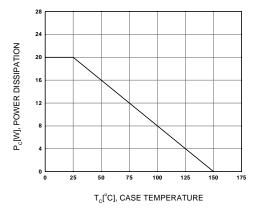
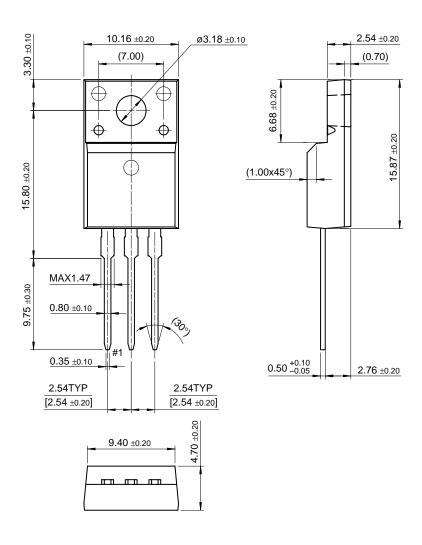


Figure 6. Power Derating

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# **Package Demensions**

# TO-220F



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